

# **CST MICROWAVE STUDIO**

## **Overview**

Ben-Gurion University.  
Course “Antennas and Radiation”.

Berezin Maksim

# View Options



Set view to „Rectangle zoom“:



Use mouse to select area to zoom.

Change the view by dragging the mouse while pressing the left button and a key:

Ctrl: Rotation

Shift: In-plane rotation

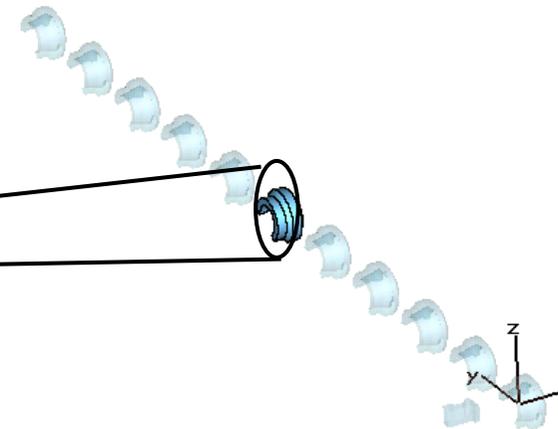
Ctrl+Shift: Panning

Other useful options:

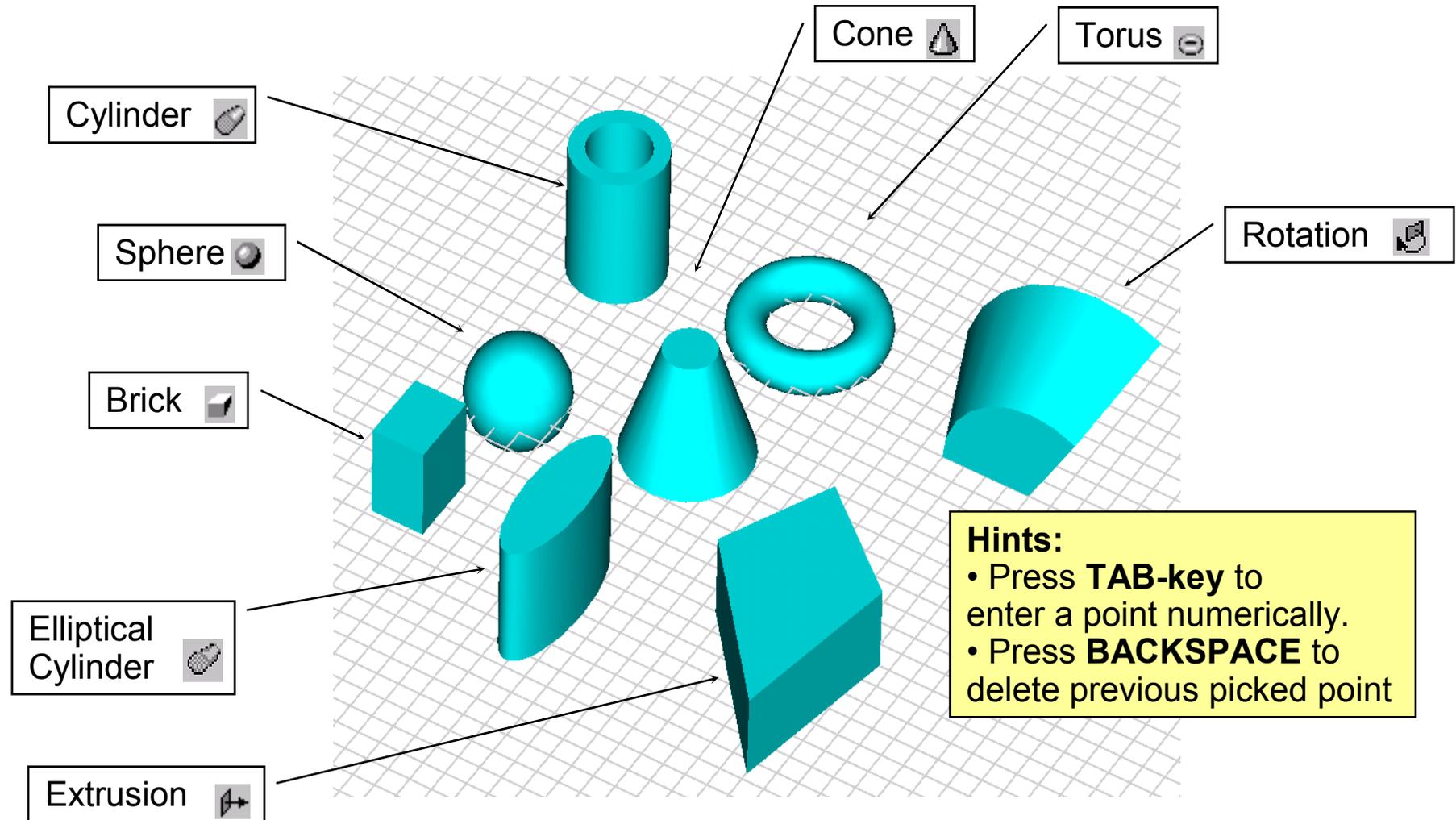
SPACE-bar: Reset View (undo zoom)

Roll (middle) mouse button: dynamic zoom

Shift – SPACE:  
Zooms into selected shape



# Primitives

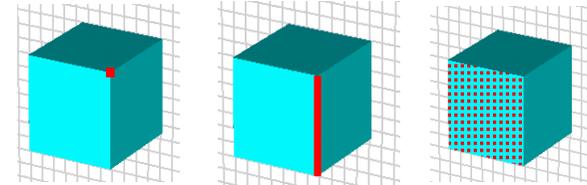


**Hints:**

- Press **TAB**-key to enter a point numerically.
- Press **BACKSPACE** to delete previous picked point

# Picks

Pick a point, an edge or an area in the structure



Select midpoint of straight edge (M)

Select edge (E)

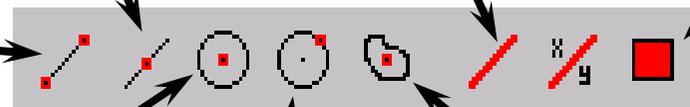
Select area (F)

Select corner point (P)

Select centerpoint of circle  
(click on circle) (C)

Select point on circle  
(click on circle) (R)

Select centerpoint of area  
(click on area) (A)

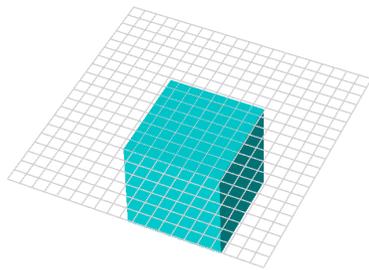
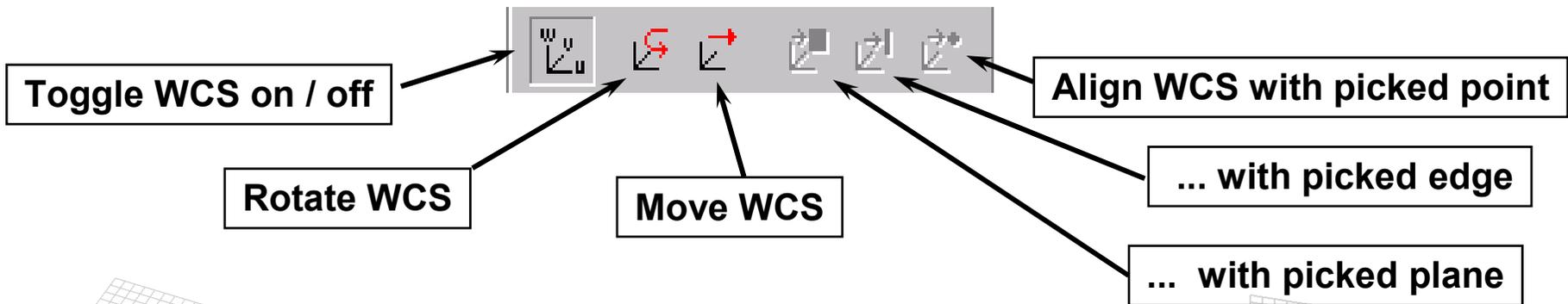


1. Activate the tool (via Icon, Menu Objects->Pick or Shortcut)
2. Double click on the point, edge or area

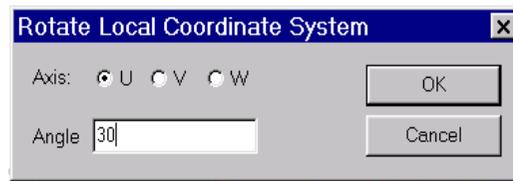
# The Local Coordinate System

To align the WCS: pick face, edge or point, then: **ShortCut = W**

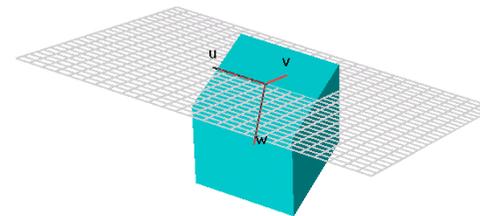
Alternative: use buttons



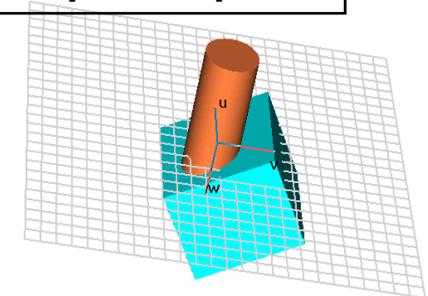
**Brick in global CS**



**Activate and rotate WCS**  + 

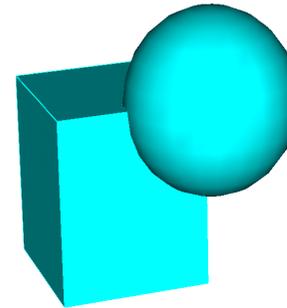
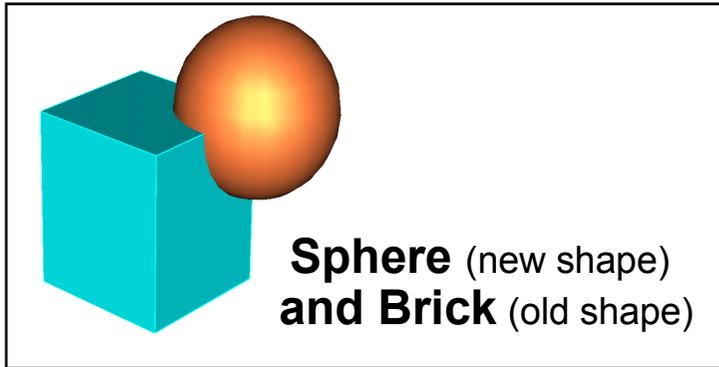
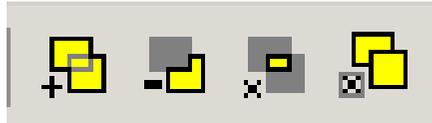


**New WCS (drawing plane)**

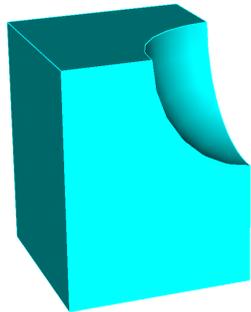


**Draw a cylinder**

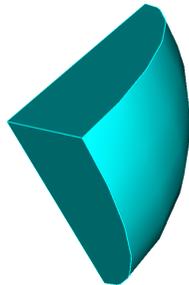
# Boolean Operations



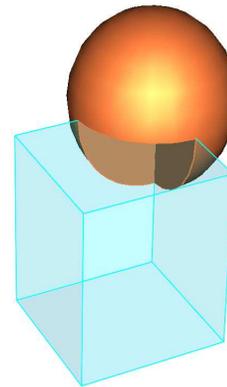
**Add**  
sphere + brick



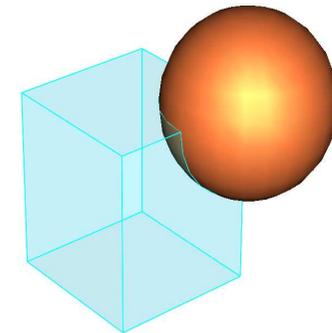
**Subtract**  
brick - sphere



**Intersect**  
brick \* sphere



**Trim**  
modifies **new** shape  
sphere / brick

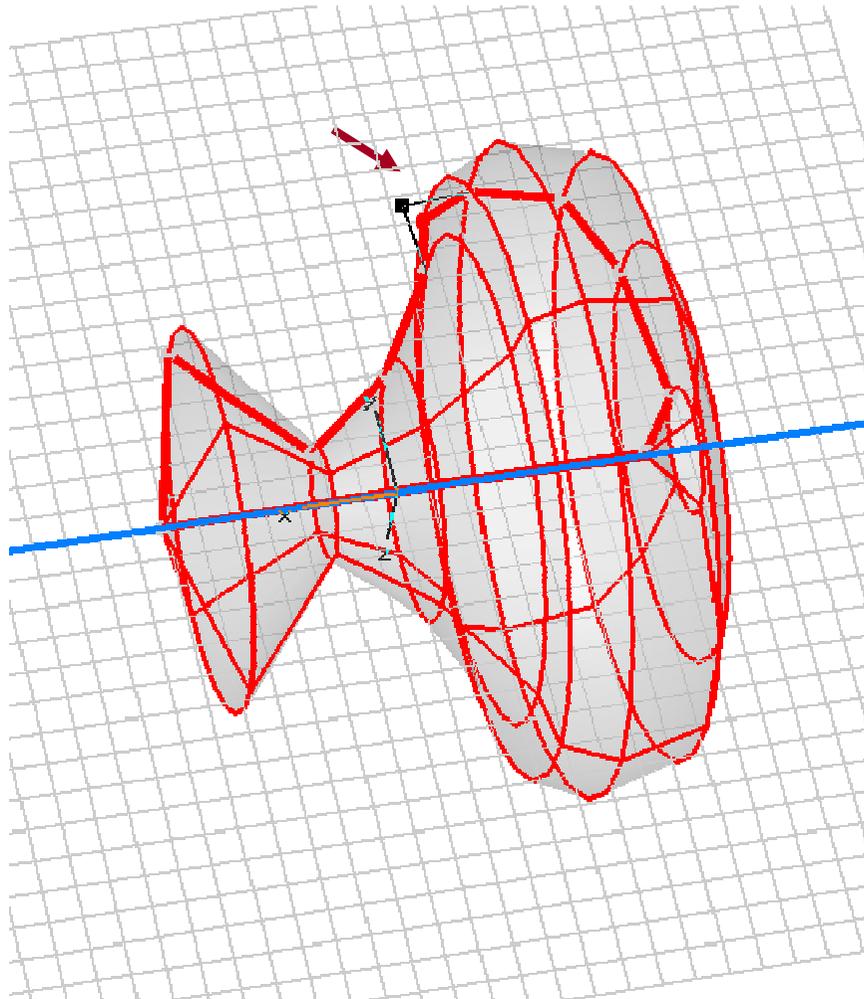


**Insert**  
modifies **old** shape  
brick / sphere



# Rotation of Profile

- Select icon and enter profile
- Avoid intersections
- Press **BACKSPACE** to delete previous picked point
- Double click corner points to move them around



**Rotate Profile**

Name:

Axis:  X  Y  Z

Start angle:  Angle:

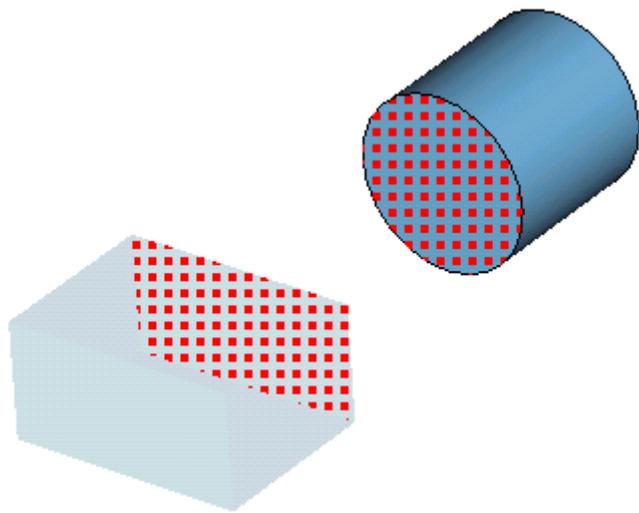
Height:  Radius ratio:  Segments per turn:

Y	X	Relative
9	-2.9	<input type="checkbox"/>
9.8	-4.5	<input type="checkbox"/>
9.1	-7.3	<input type="checkbox"/>
6.3	-8.4	<input type="checkbox"/>
1.9	-8.9	<input type="checkbox"/>

Component:  Material:

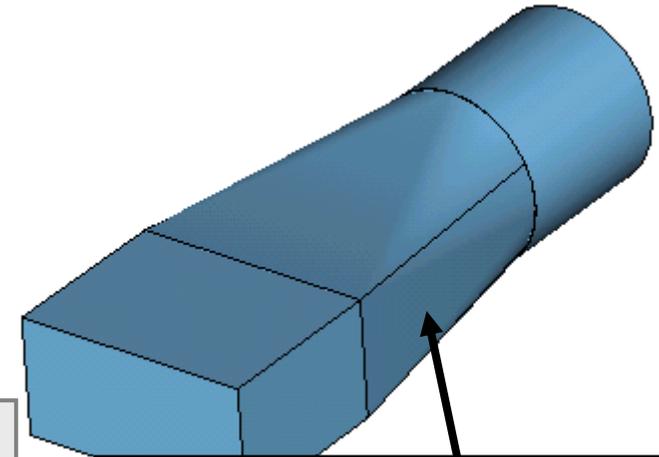
# Loft-Operation

Two picked faces,  
to be connected by new shape

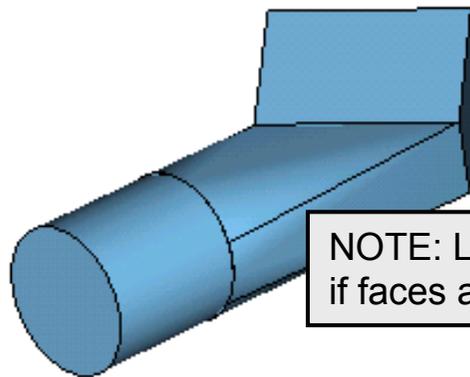


Loft-Operation

Objects -> Loft...

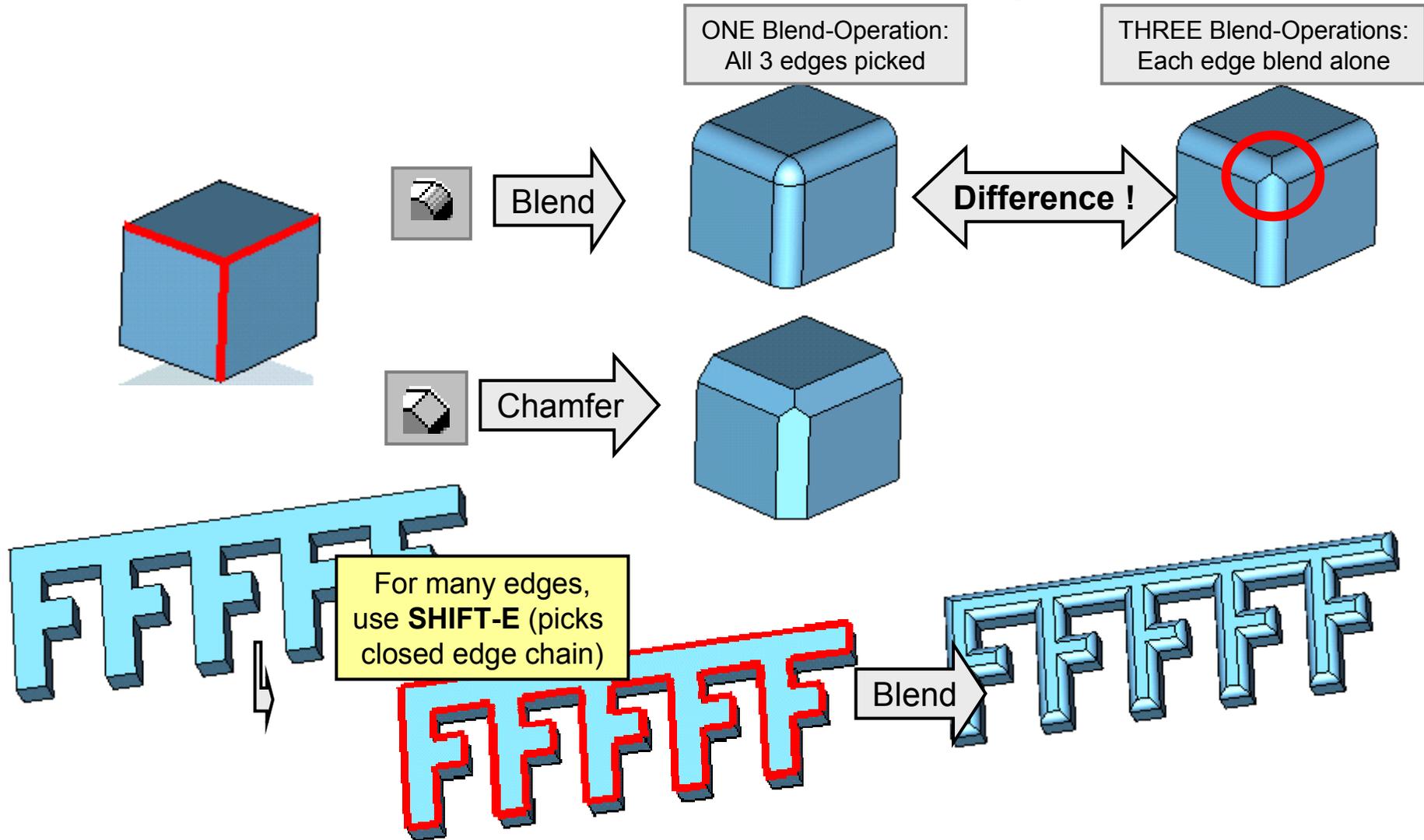


The new shape's profile  
is morphed from the first  
picked face into the second.



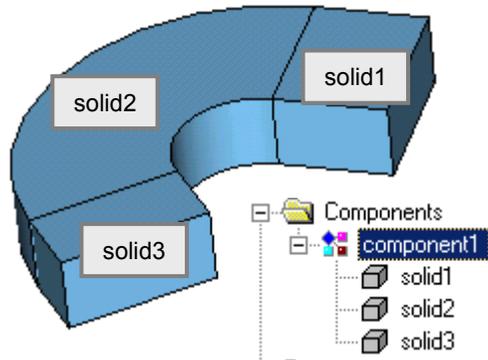
NOTE: Loft is even possible,  
if faces are not parallel

# Blend and Chamfer Edges



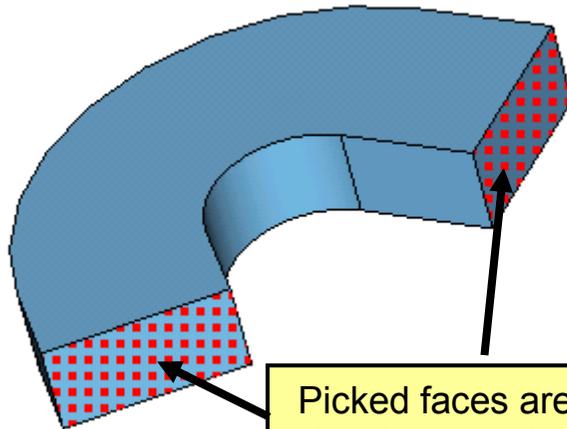
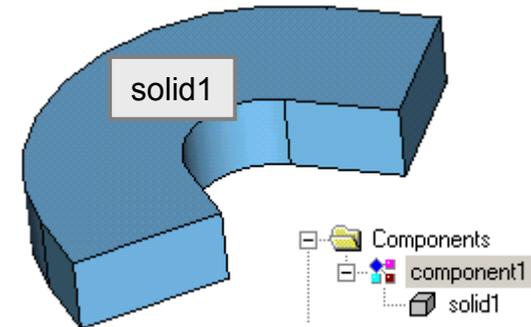
# Shell-Operation

**TASK:** Waveguide-Bend, consisting of three shapes, should be shelled



Combine to ONE shape

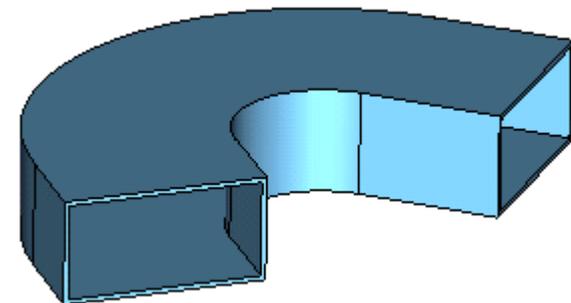
1. Select component1
2. Objects -> Merge Materials on Component



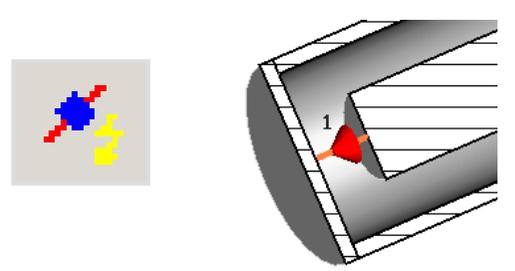
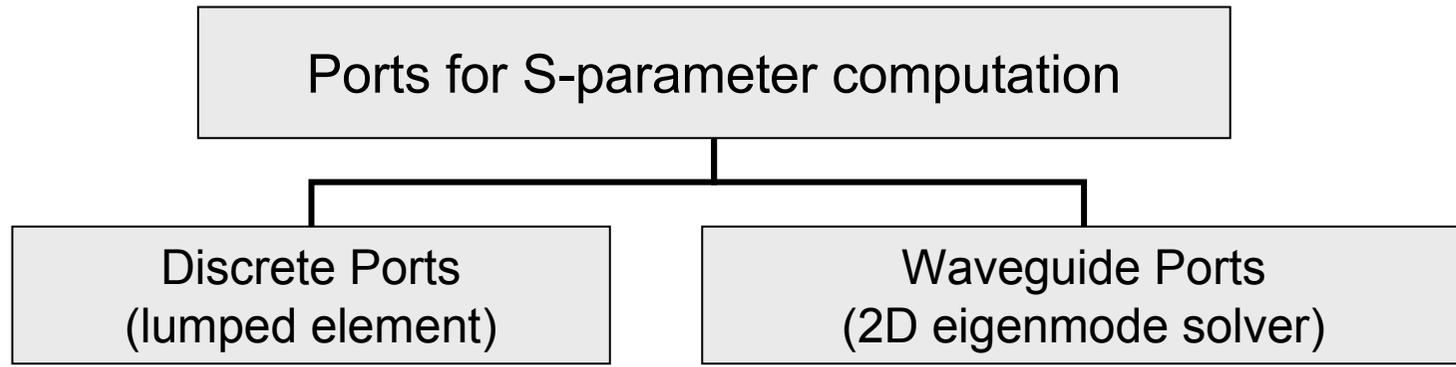
Picked faces are **open** after Shelling-Operation

Objects -> Shell...

1. Picked faces, to be open after shelling
2. Select solid1, to be shelled

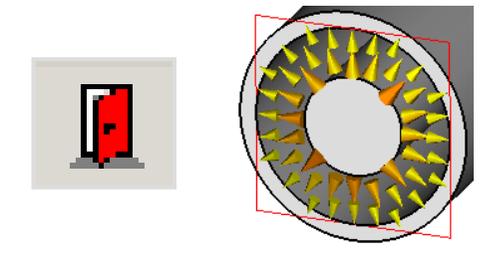


# Definition of Ports



Input: Knowledge of TEM-Mode  
Line Impedance

Output: Voltage and Current



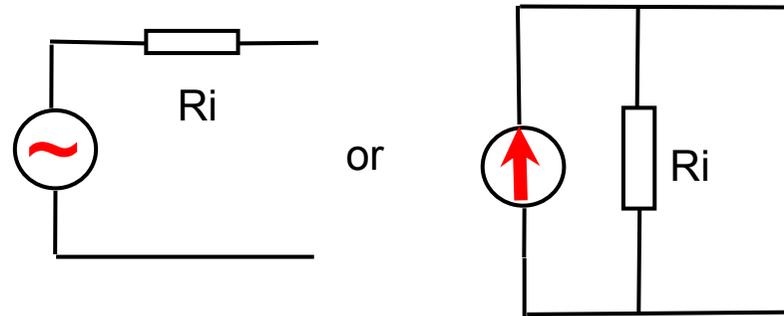
Input: Area for eigenmode solution

Output: E and H-Pattern,  
Line Impedance,  
Prop.constant (beta+alpha)

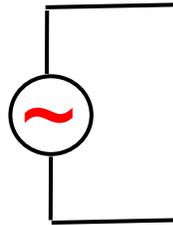
- Discrete ports can be used for TEM-like modes, not for higher modes ( $f_{\text{cutoff}} > 0$ ).
- Waveguide Ports deliver better match to the mode pattern as well as higher accuracy in S-Parameters.

# Discrete Ports

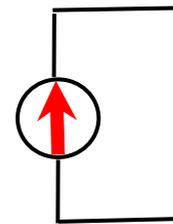
S parameter port



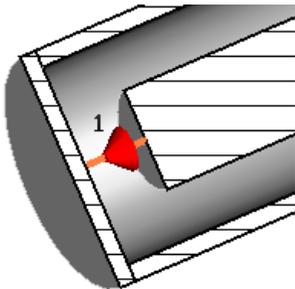
2. Voltage port



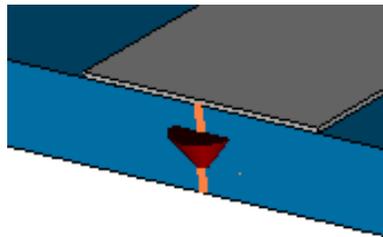
3. Current



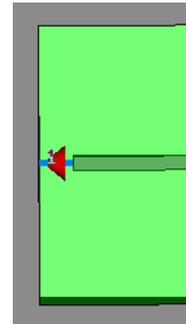
**Coaxial**



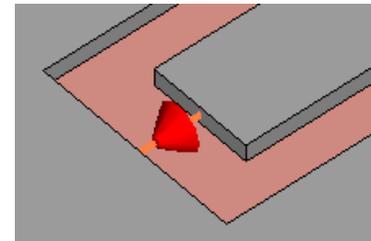
**Microstrip**

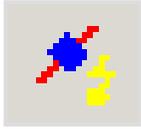


**Stripline**



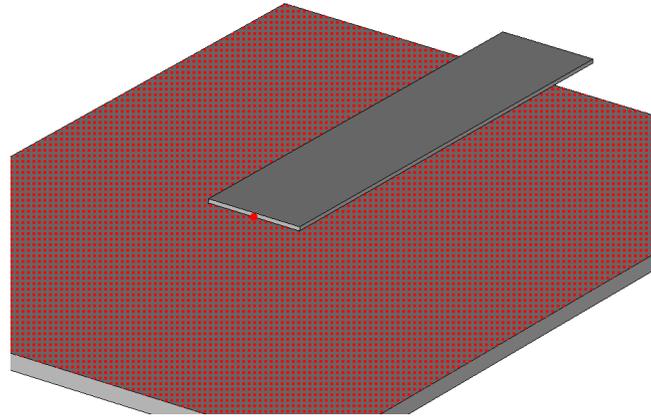
**Coplanar Waveguide**





# Discrete Port Definition

pick 2 points  
(or)  
1 point and a face  
(or)  
enter coordinates  
(not recommended)



Select Port Type  
and Impedance

**Discrete Port**

Port type

S-Parameter

Voltage

Current

Properties

Name: 1

Impedance: 50.0 Ohms

Monitor voltage and current

Location

X1	Y1	Z1
3.5	0.6	6
X2	Y2	Z2
3.5	0.2	6

Use picked points as location

Swap points

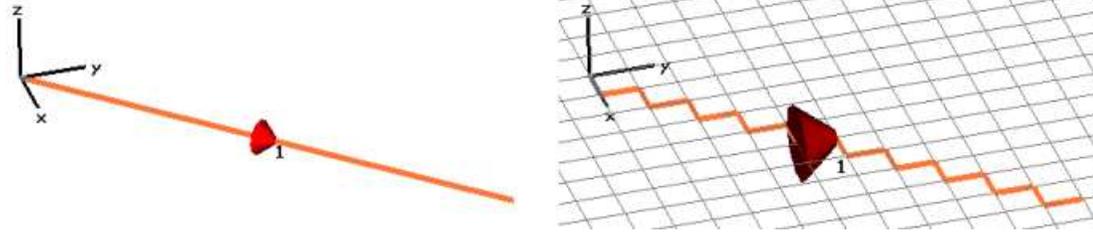
OK

Cancel

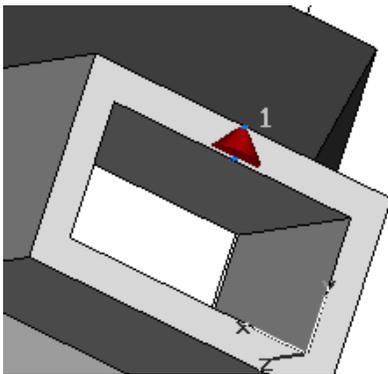
Help

# Discrete Port Details

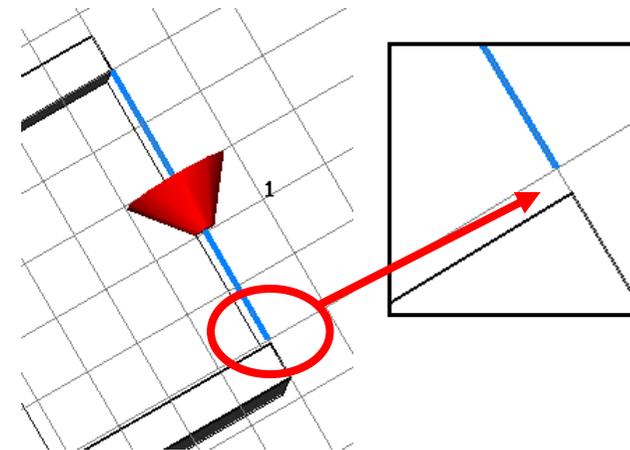
Mesh



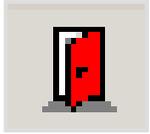
1. The port is the cone on the mesh edge
2. That edge must be a dielectric edge
3. The wires attach the port to the structure



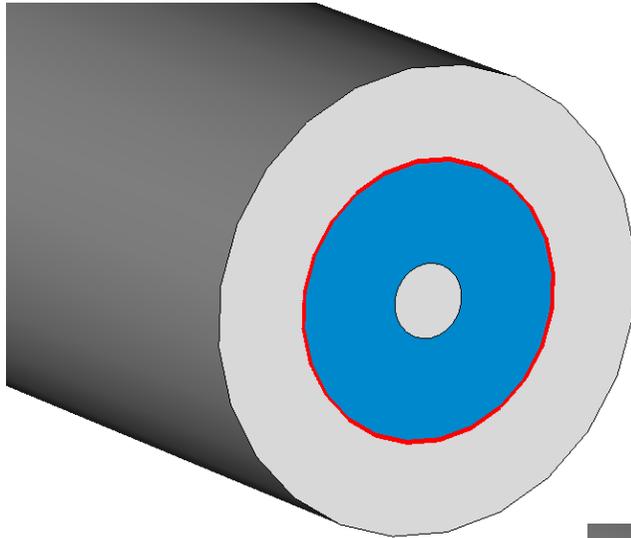
In metal



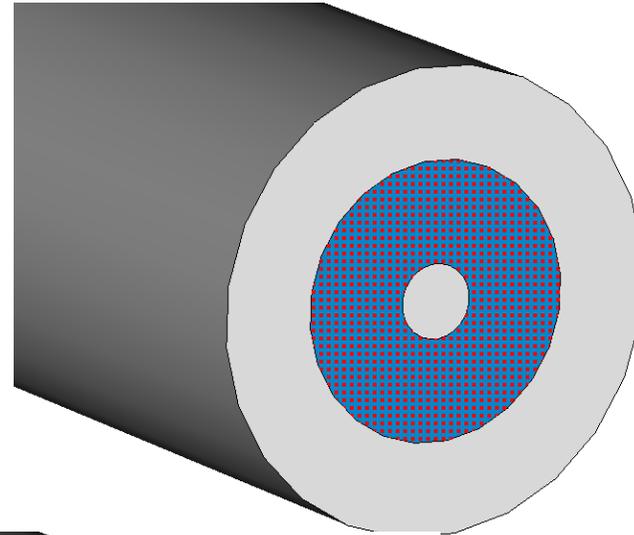
Open



# Waveguide Port Definition

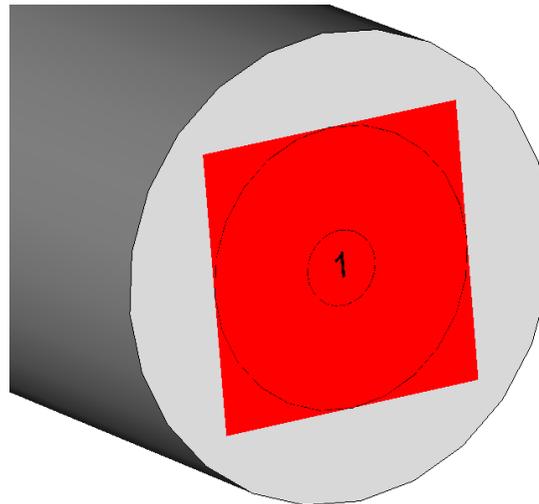


Pick Edge



Pick Face

Also possible: any combination  
of pick points, edges, faces



# Waveguide Port Definition

**Waveguide Port**

**General**

Name: 1

Normal:  X  Y  Z

Orientation:  Positive  Negative

Text size: > large

**Position**

Coordinates:  Free  Full plane  Use picks

Xmin: -2.9 - 0.0 Xmax: 2.4 + 0.0

Ymin: -3.5 - 0.0 Ymax: 3.8 + 0.0

Free normal position Zpos: 7.6

**Reference plane**

Distance to ref. plane: 0

**Mode settings**

Multipin port

Define Pins...

Impedance and calibration

Define Lines...

Number of modes: 1

Polarization angle

0.0

Buttons: OK, Apply, Preview, Cancel, Help

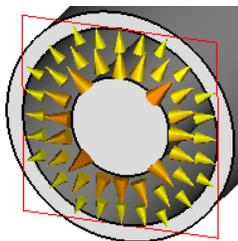
In addition to pick point, Full Plane or Free Coordinates can also be specified

For Phase Deembedding

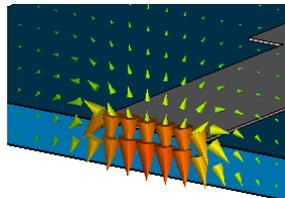
Number of desired Higher Order Modes

For Separation of Degenerate Modes in Circular Waveguides

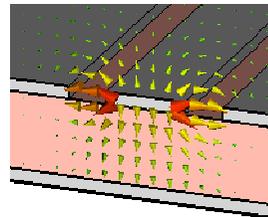
Coaxial



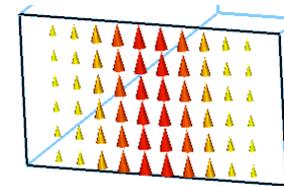
Microstrip



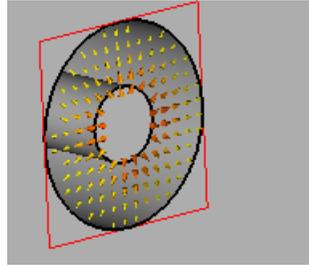
Coplanar Waveguide



Hollow Waveguide

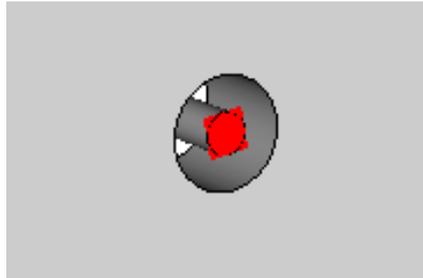


# Waveguide Port Details

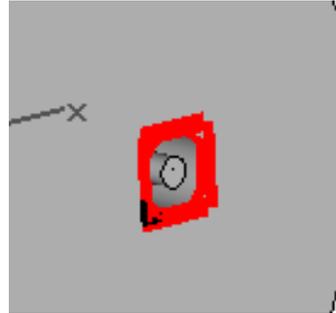


Port must be large enough to cover the fields of the port mode of interest.

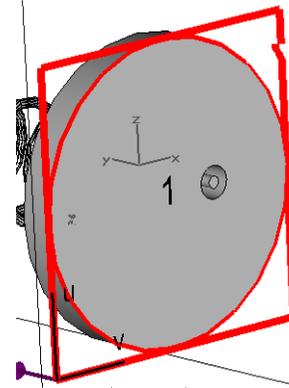
NO, Too small



YES, Good

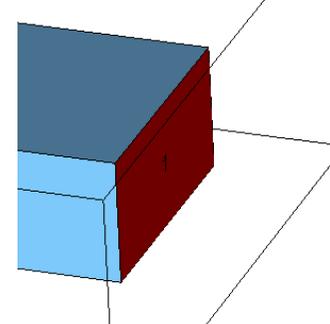
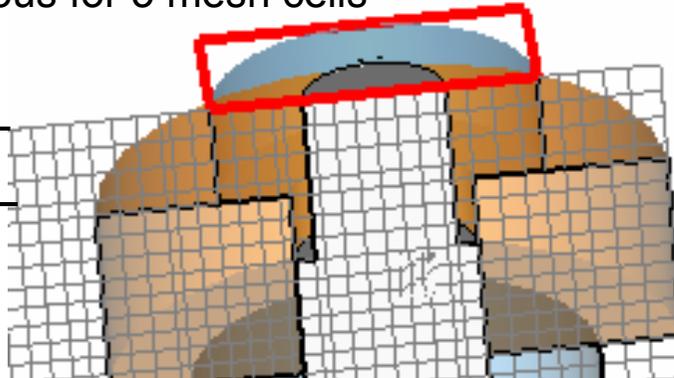


NO, Unnecessarily large



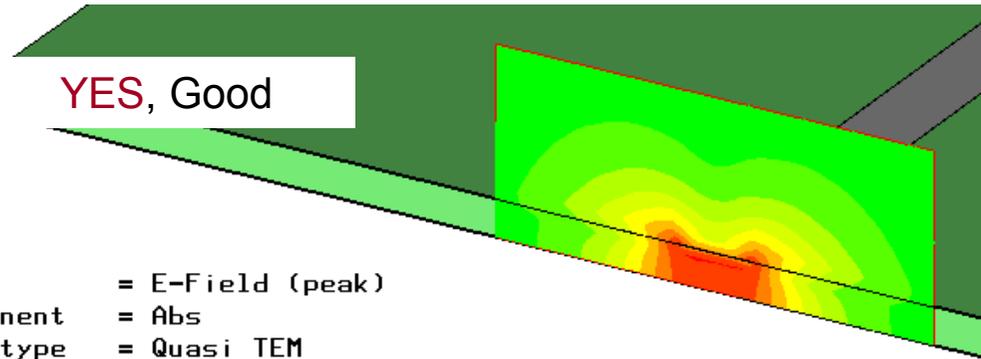
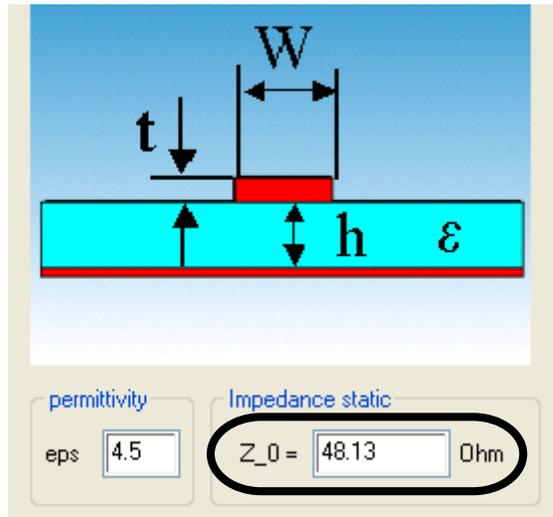
Time Domain: Geometry must be homogenous for 3 mesh cells

3 mesh cells



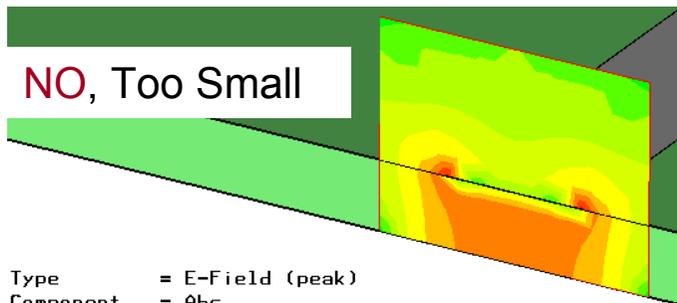
Frequency Domain: Internal port must be backed by PEC

# Port Impedance Evaluation



YES, Good

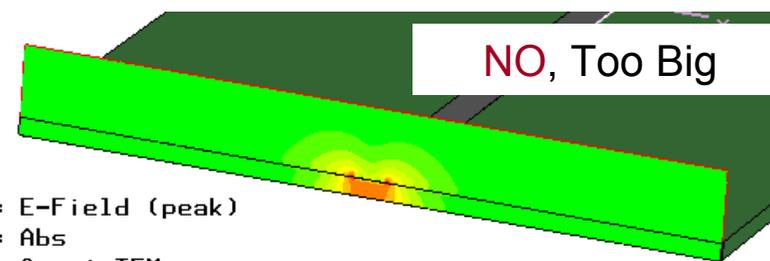
Type = E-Field (peak)  
 Component = Abs  
 Mode type = Quasi TEM  
 Accuracy = 2.05515e-015  
 Beta = 414.615 1/m  
 Wave Imp. = 105.773 Ohms  
 Line Imp. = 47.3669 Ohms



NO, Too Small

Type = E-Field (peak)  
 Component = Abs  
 Mode type = Quasi TEM  
 Accuracy = 4.78951e-014  
 Beta = 397.253 1/m  
 Wave Imp. = 228.267 Ohms  
 Line Imp. = 44.2542 Ohms

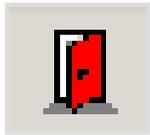
Plane at z = 100  
 Frequency = 10  
 Phase = 0 degrees  
 Maximum-2d = 8187.01 V/m at 2.5 / 2.5 / 100



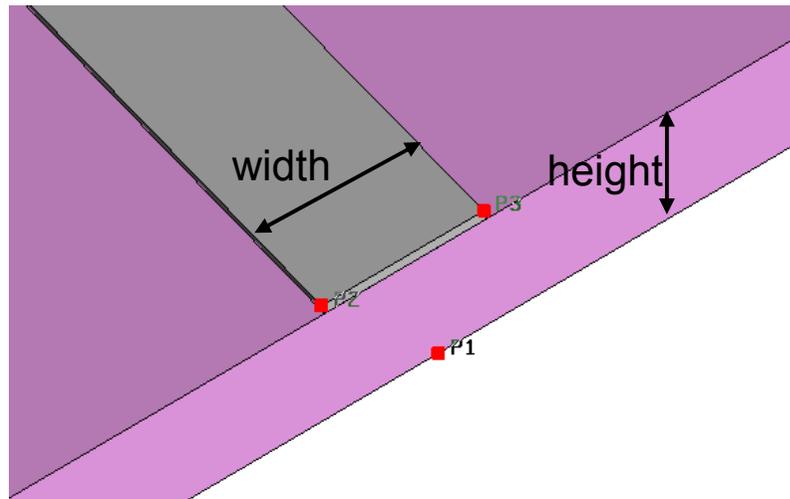
NO, Too Big

Type = E-Field (peak)  
 Component = Abs  
 Mode type = Quasi TEM  
 Accuracy = 3.32717e-011  
 Beta = 414.039 1/m  
 Wave Imp. = 218.718 Ohms  
 Line Imp. = 46.8217 Ohms

Plane at z = 100  
 Frequency = 10  
 Phase = 0 degrees  
 Maximum-2d = 7878.96 V/m at 2.5 / 2.5 / 100



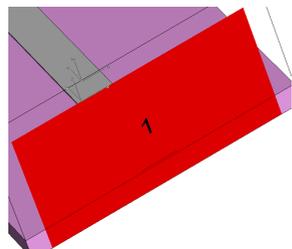
# Port Definition - Microstrip Line



1) Pick 3 Points

2) Enter Port menu

3) Adjust additional port space  
(+/- 5 width, +5 height)



**Waveguide Port**

**General**

Name: 1

Normal:  X  Y  Z

Orientation:  Positive  Negative

Text size: > large

**Position**

Coordinates:  Free  Full plane  Use picks

Xmin: -0.7 - 5\*width Xmax: 0.2 + 5\*width

Zmin: -0.1 - 0.0 Zmax: 1 + 5\*height

Free normal position Ypos: -3.5

**Reference plane**

Distance to ref. plane: 0

**Mode settings**

Multipin port Number of modes: 1

Impedance and calibration  Polarization angle

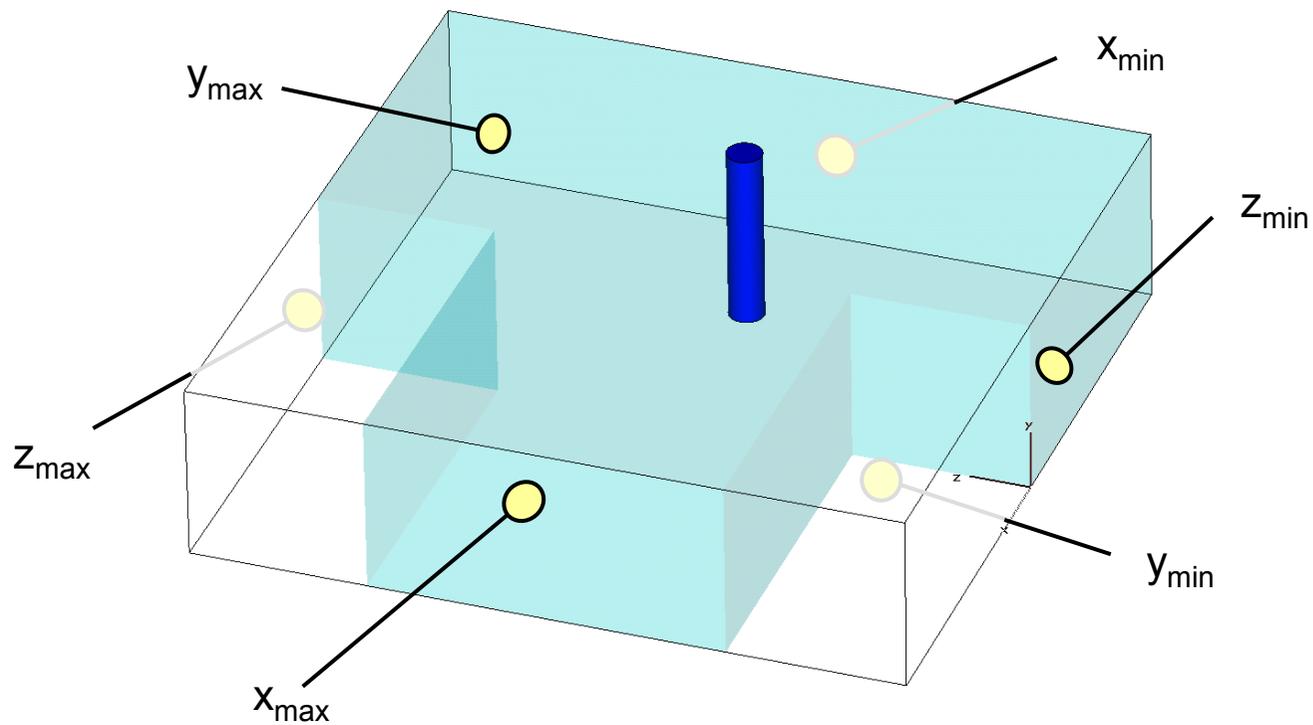
Define Pins... Define Lines... 0.0

# **Boundary Conditions**

# Boundaries

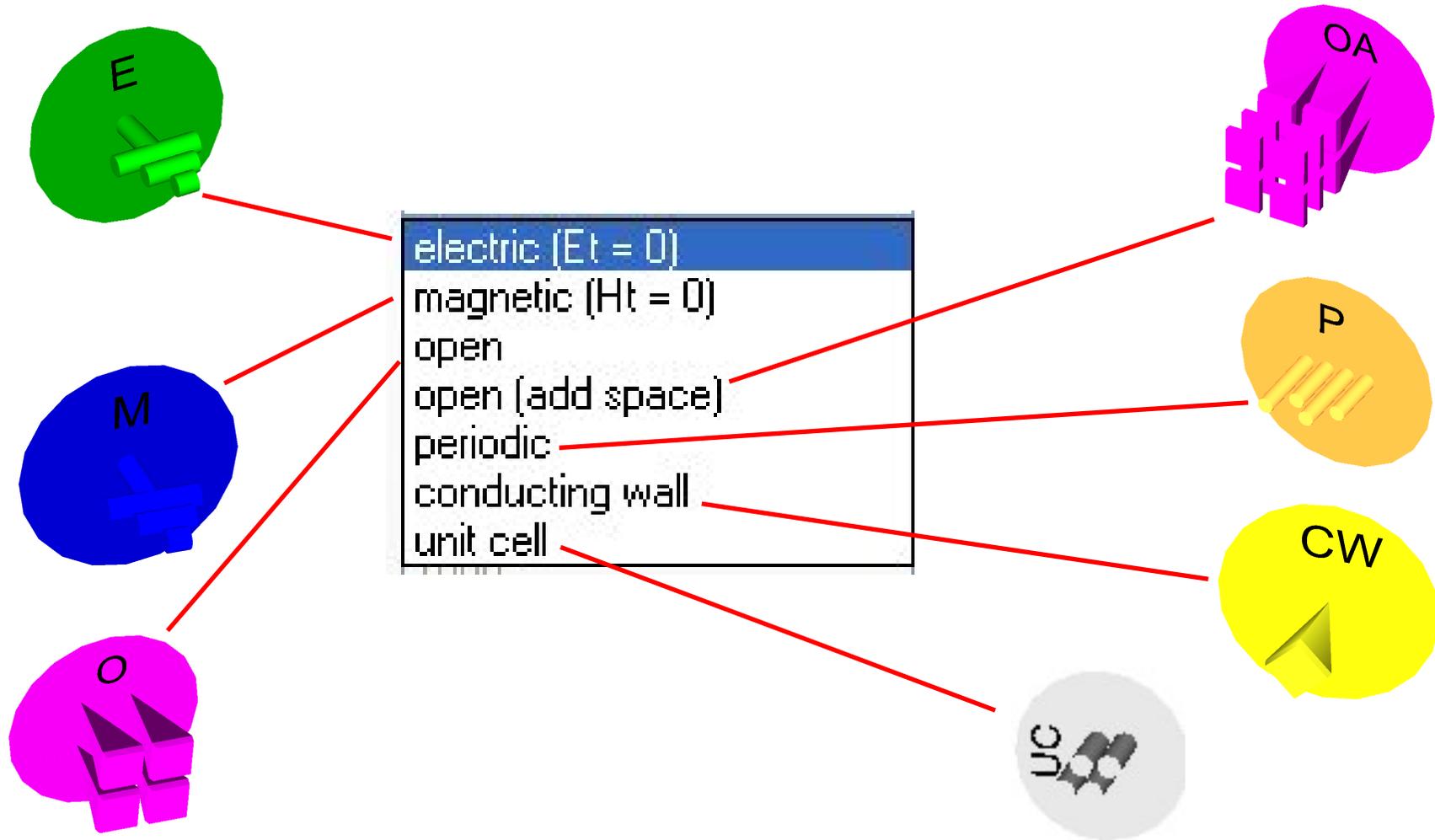
CST MWS uses a rectangular grid system, therefore also the complete calculation domain is of rectangular shape => 6 boundary surfaces have to be defined at the minimum and maximum position in each co-ordinate direction ( $x_{\min}$ ,  $x_{\max}$ ,  $y_{\min}$ ,  $y_{\max}$ ,  $z_{\min}$ ,  $z_{\max}$ ).

Example: T-Splitter



# Boundary settings (1)

7 different settings are available



# Boundary settings (2)



Electric boundaries (Default setting): No tangential electric field at surface.



Magnetic boundaries: No tangential magnetic field at surface. Default setting for waveguide port boundaries.



Open boundaries: Operates like free space – waves can pass this boundary with minimal reflections. Perfectly matched layer (PML) condition.



Open add space boundaries: Same as Open, but adds some extra space for farfield calculation (automatically adapted to center frequency of desired bandwidth). *This option is recommended for antenna problems.*



Conducting wall: Electric conducting wall with finite conductivity (defined in Siemens/meter).

# Boundary settings (3)



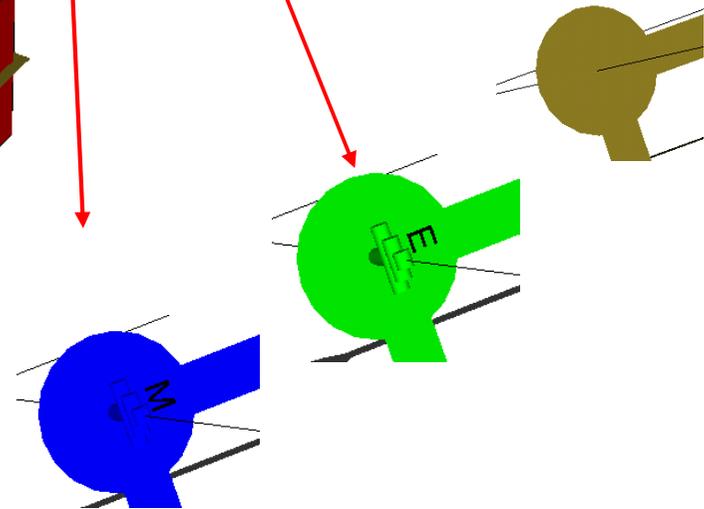
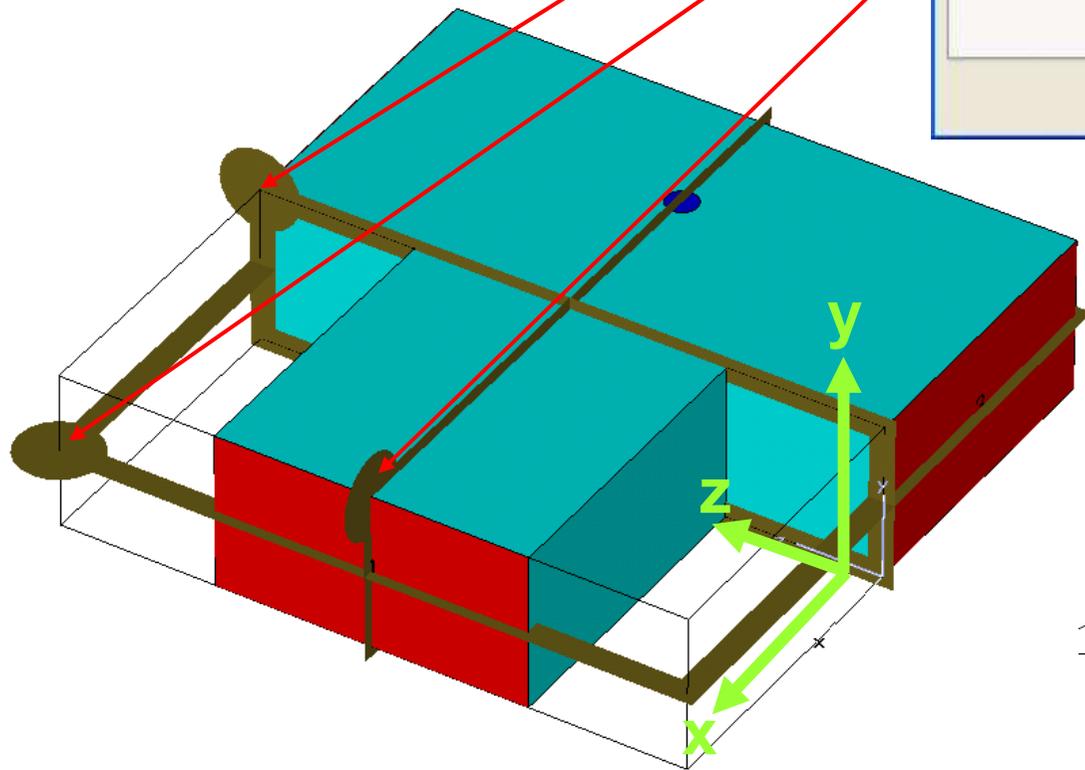
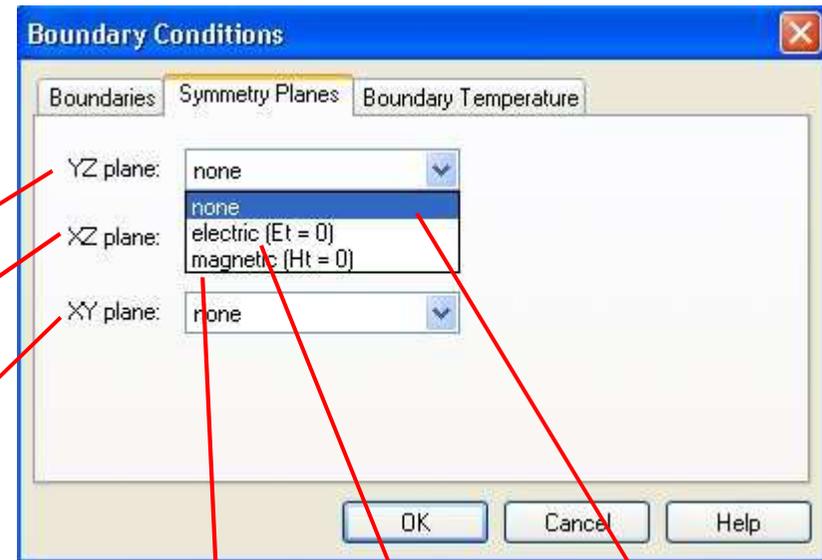
Periodic boundaries: Connects two opposite boundaries so that the calculation domain is simulated to be periodically expanded in the corresponding direction. Thus it is necessary that both boundaries facing each other are always indicated as periodic. *The resulting structure represents an infinite expanded antenna pattern, phased array antennas.* F! Hex mesh, T! + 0 phase shift



Unit Cell: Used with F! Solver, Tet mesh, similar to F! Periodic boundary with Hex mesh. A two dimensional periodicity **other than in direction of the coordinate axes** can be defined. If there are open boundaries perpendicular to the Unit Cell boundaries, they are realized by **Floquet modes**, similar to modes of a wave guide port .

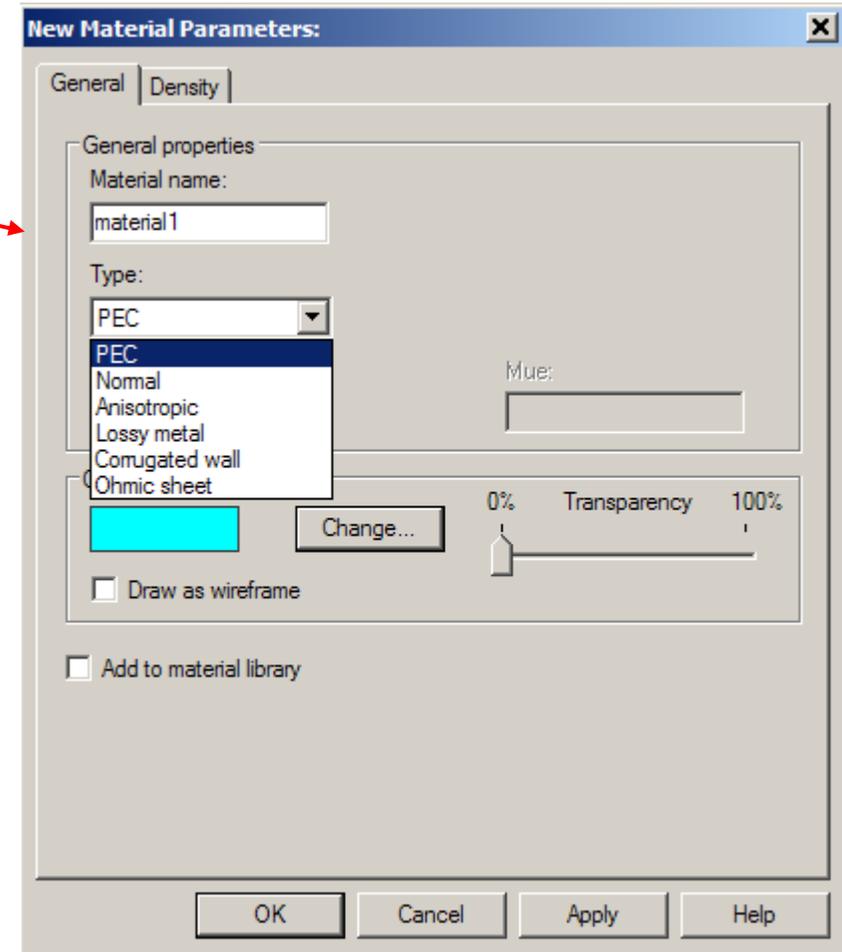
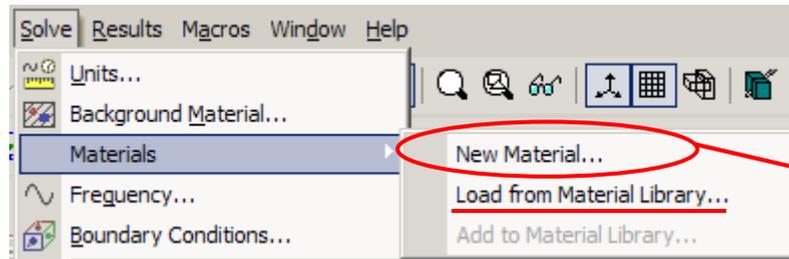
# Boundaries : Symmetry planes

3 different settings are available for  
3 possible symmetry planes:



# Materials

# Basic Materials



PEC: **P**erfect **E**lectric **C**onductor →  $\sigma = \infty$

Normal: General material model → Typically used for dielectric materials

Anisotropic:  $\epsilon$  and  $\mu$  are directionally dependent  
 $\sigma \neq \infty$

Lossy Metal: Conductor →

Corrugated wall: Surface impedance

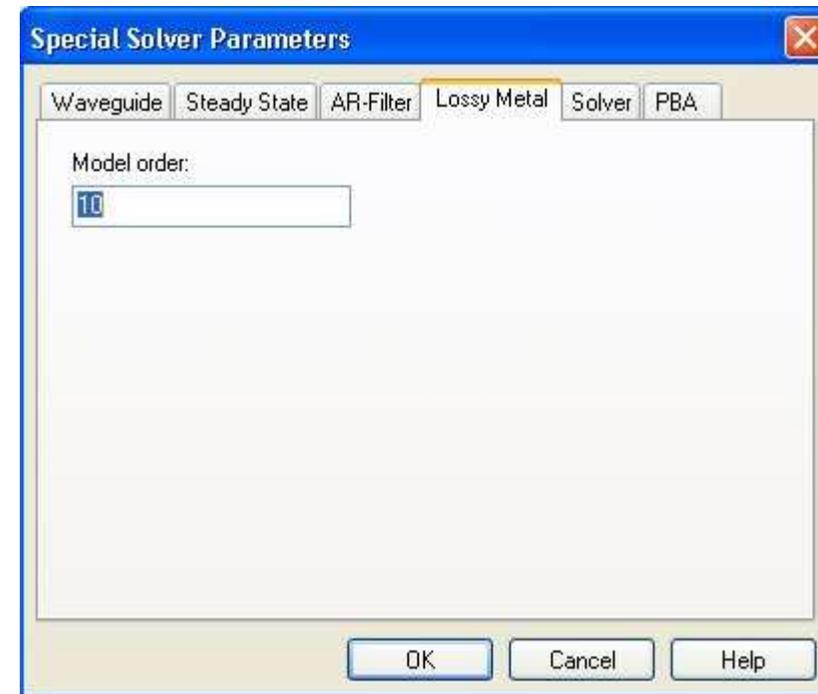
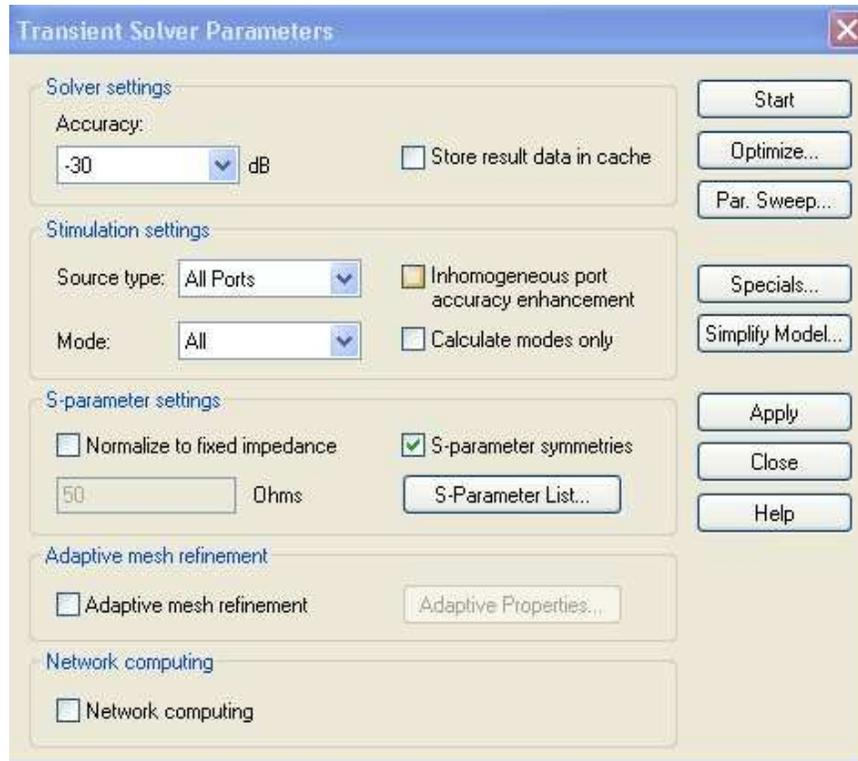
$$Z = j \frac{w}{w+t} \sqrt{\frac{\mu_0}{\epsilon_0}} \tan(k_0 d)$$

Ohmic sheet: Surface impedance [ $\Omega/\square$ ]

# Lossy Metal

- Why is it required?
  - Sampling of skin depth would require very fine mesh steps at the metal surface and defining conductor as a normal material  
(skin depth for copper at 1 GHz approx. 2  $\mu\text{m}$ )
  - This results in a very small timestep, which leads to a very long simulation time
- Solution:
  - 1D Model which takes skin depth into account without spatial sampling.

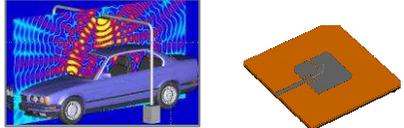
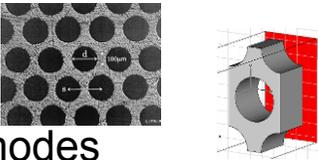
# Lossy Metal



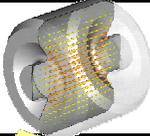
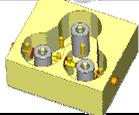
# **Solver Selection**

# CST MICROWAVE STUDIO® Solvers

## General Purpose Solver 3D-Volume

	<b>Transient</b>	<ul style="list-style-type: none"> <li>▪ Large problems</li> <li>• Broadband</li> <li>• Arbitrary time signals</li> </ul>	
	<b>Frequency Domain</b>	<ul style="list-style-type: none"> <li>▪ Narrow band / single frequency</li> <li>• Small problems</li> <li>• Periodic structures with Floquet port modes</li> </ul>	

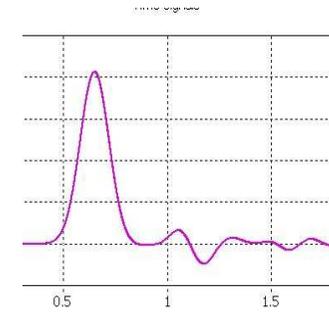
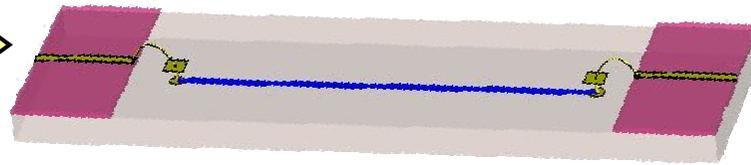
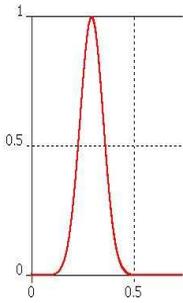
## Special Solver 3D-Volume: Closed Resonant Structures

	<b>Eigenmode</b>	<ul style="list-style-type: none"> <li>▪ Strongly resonant structures, narrow band</li> <li>• Cavities</li> </ul>		
<b>Resonant</b>		<b>FD, Resonant</b>	<ul style="list-style-type: none"> <li>▪ Strongly resonant, closed structures</li> </ul>	

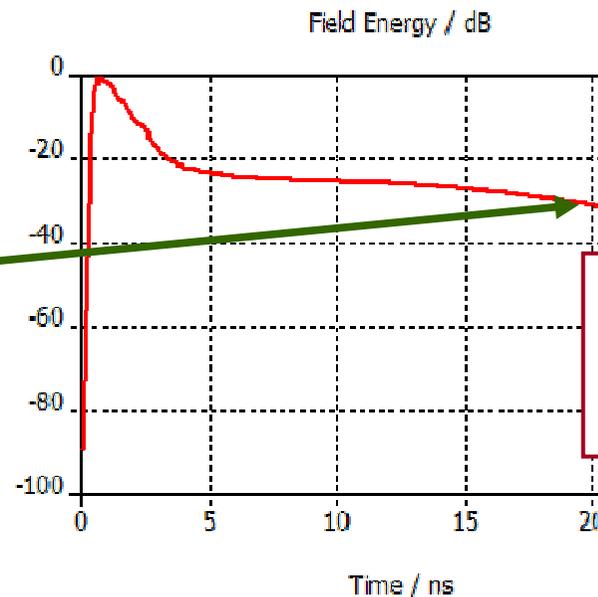
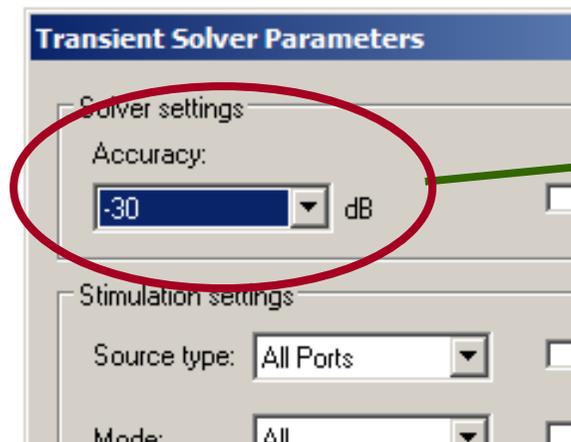
## Special Solver 3D-Surface: Large open metallic structures

	<b>Integral Equation solver (based on MLFMM)</b>	<ul style="list-style-type: none"> <li>▪ Large structures</li> <li>▪ Dominated by metal</li> </ul>	
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# Transient Solver Introduction



- Begin with no energy inside calculation domain
- Inject energy and step through time
- As time progresses, energy inside calculation domain decays
- When energy decays “far enough,” the simulation stops

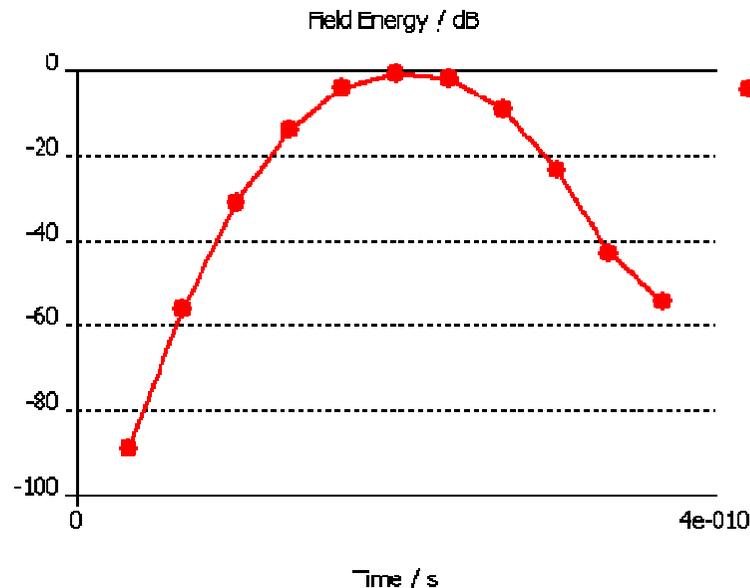


- Hexahedral mesh only
- Time and Frequency Domain Results
- All frequencies in one simulation

# !T – Time Domain Solver

## Overview

- Arbitrary input signal
- Inject energy and watch it leave
- Solve for unknowns without matrix inversion
- Hexahedral Mesh: Broadband meshing and results
- Simulation is performed on a port-by-port basis
- Smaller mesh cells = longer solve times
- Energy storage for high Q structures prolongs simulation time

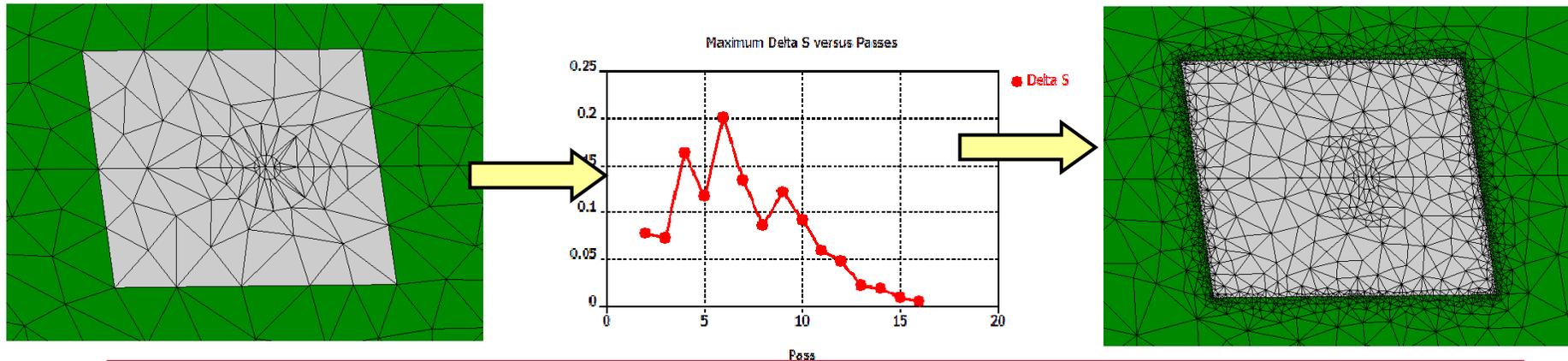


The transient solver is very robust and can handle most applications.

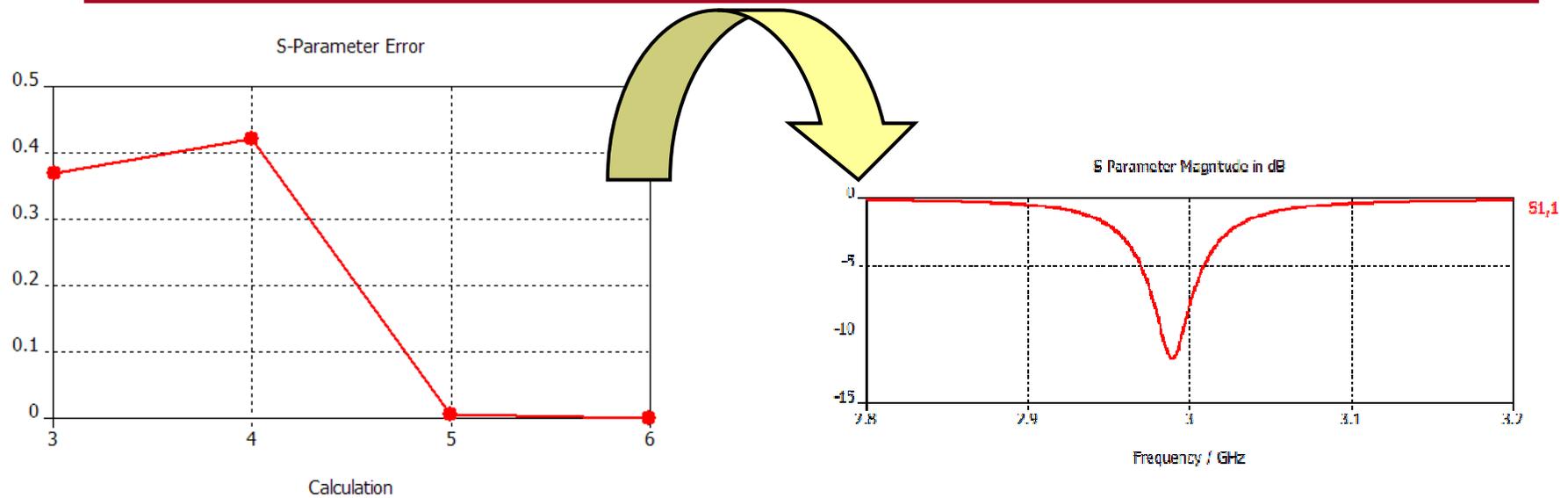
Well suited applications: Broadband, electrically large structures.

Highly resonant, electrically small structures may be better suited to the frequency domain solver.

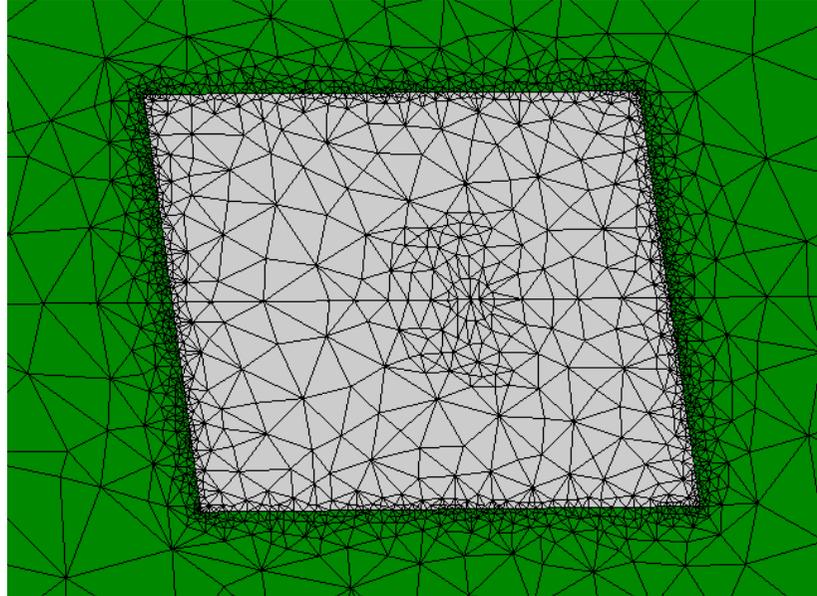
# Frequency Solver Introduction



- Simulation performed at single frequencies
- Broadband Frequency Sweep to achieve accurate S-Parameters
- very robust automatic mesh refinement (easy to learn)
- ➔ 2nd General Purpose Solver (besides Time Domain)



# !F – Frequency Domain Solver

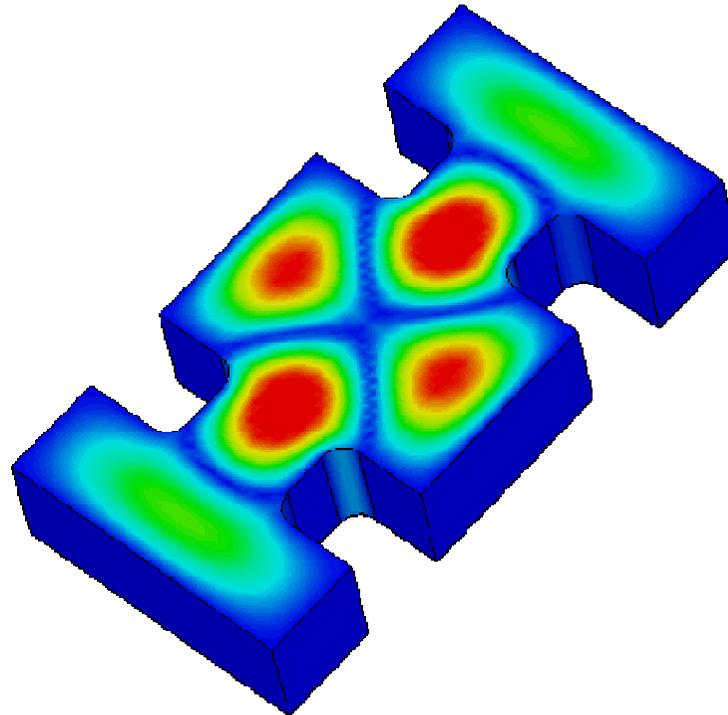


The frequency domain solver is very robust and can handle most applications.

Well suited applications: Narrowband, electrically small structures.

Limited computational resources make it necessary to use the time domain solver for electrically large structures.

# !E – Eigenmode Solver

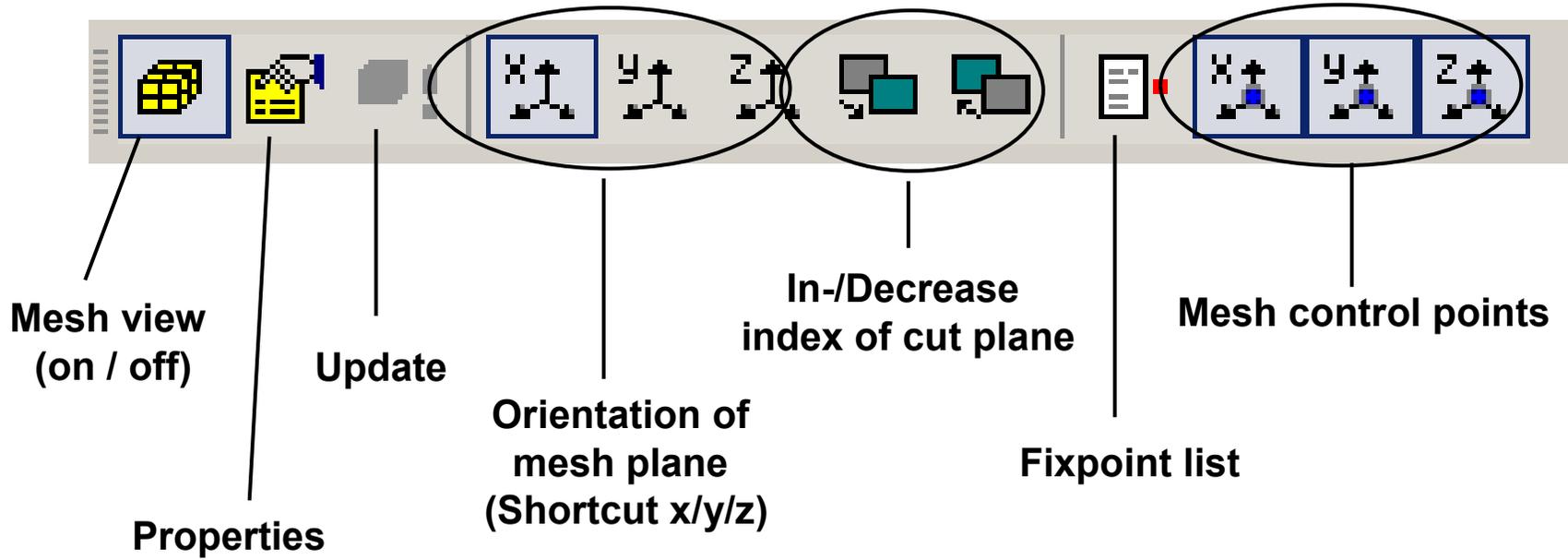


The eigenmode solver is a very specialized tool for closed cavities. No s-parameters are generated, only eigenmodes which are single frequency results.

Well suited applications: Narrow band, resonant cavities.

# **Meshing: The Basics**

# Mesh Generation





# Global Mesh Properties- Hexahedral

Define size of the **biggest** mesh step

Limitation for the **smallest** mesh step

The screenshot shows the 'Mesh Properties' dialog box with the following settings:

- Mesh type: Hexahedral
- Mesh density control:
  - Lines per wavelength: 10
  - Lower mesh limit: 10
  - Mesh line ratio limit: 10.0 (selected)
  - Smallest mesh step: 0.0
- Automatic mesh generation:
- Mesh summary:

Min. mesh step:	Nx:
0.146447	13
Max. mesh step:	Ny:
0.435397	4
Meshcells:	Nz:
1764	50

**Lines Per Wavelength** defines the minimum number of mesh lines in each coordinate direction based on the highest frequency of evaluation.

**Lower Mesh Limit** defines a minimum distance between two mesh lines for the mesh by dividing the diagonal of the smallest bounding box face by this number.

**Ratio Limit** defines ratio between the biggest and smallest distance between mesh lines. Increase for mesh quality when high aspect ratios exist, e.g. edge coupled microstrip. Alternative to ratio limit, the **Smallest mesh step** can be entered directly as absolute value rather than defining it relatively via biggest mesh step and ratio limit.

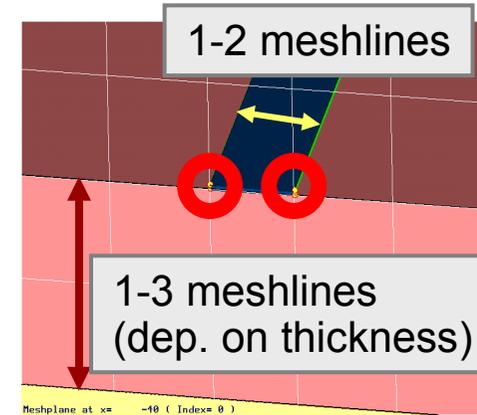
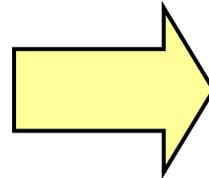
**Smallest mesh step determines simulation speed !**

# Required Initial Discretization

## 1) Microstrip + cpw

Required meshlines:

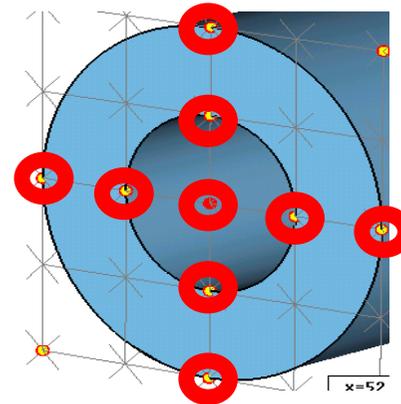
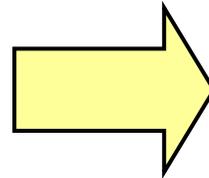
- **each straight PEC-edge (for each slot + stripline)**  
(metal thickness does not need 2 meshlines)



## 2) Coaxial

Required meshlines:

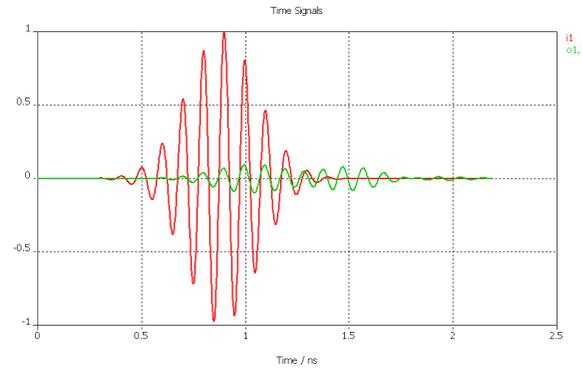
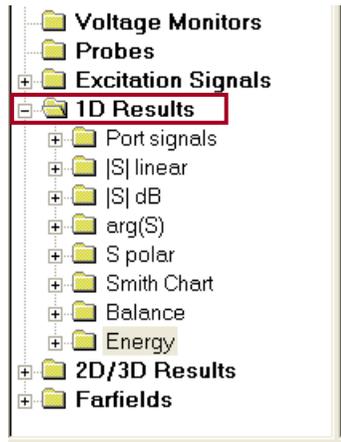
- **coax-center**
- **INNER radius of dielectric**
- **OUTER radius of dielectric**



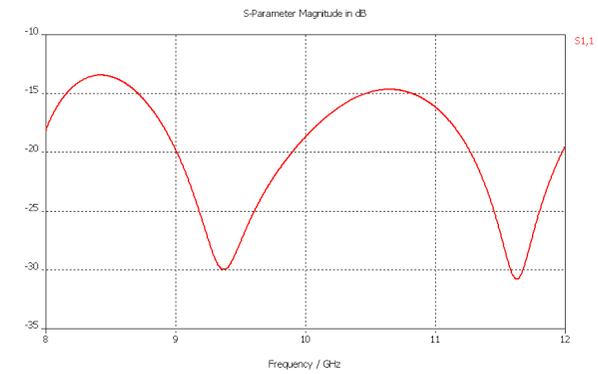
# **CST MWS - Standard workflow**

- Choose Project Template
- Parameters + Geometry + Materials
- Ports
- Frq-Range + Boundaries / Symmetries
- Monitor Definition
- Quick Check Meshing
- Run Simulation

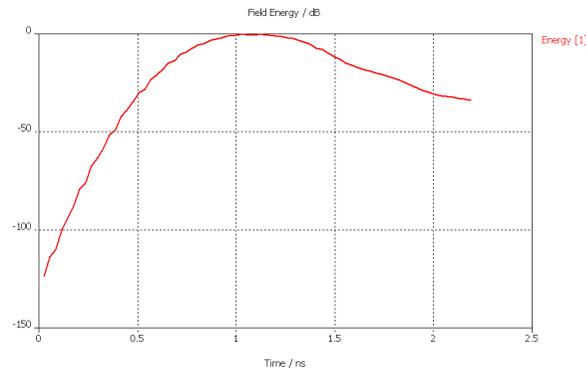
# Analyze 1D Results



Port Signals

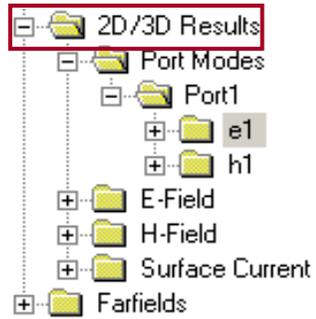


S Parameter

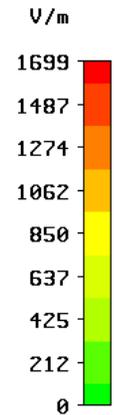
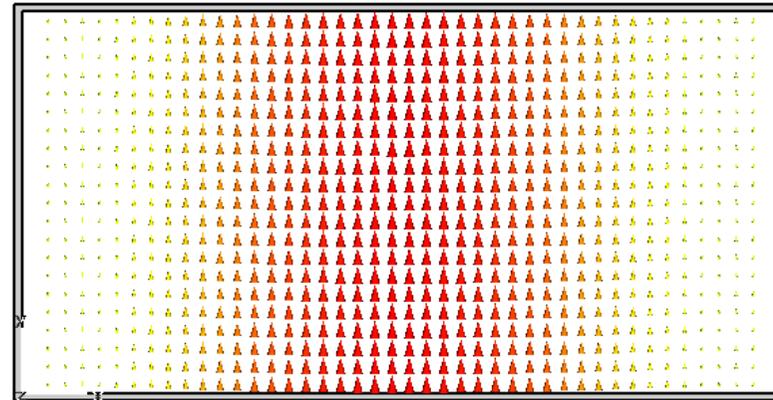


Energy

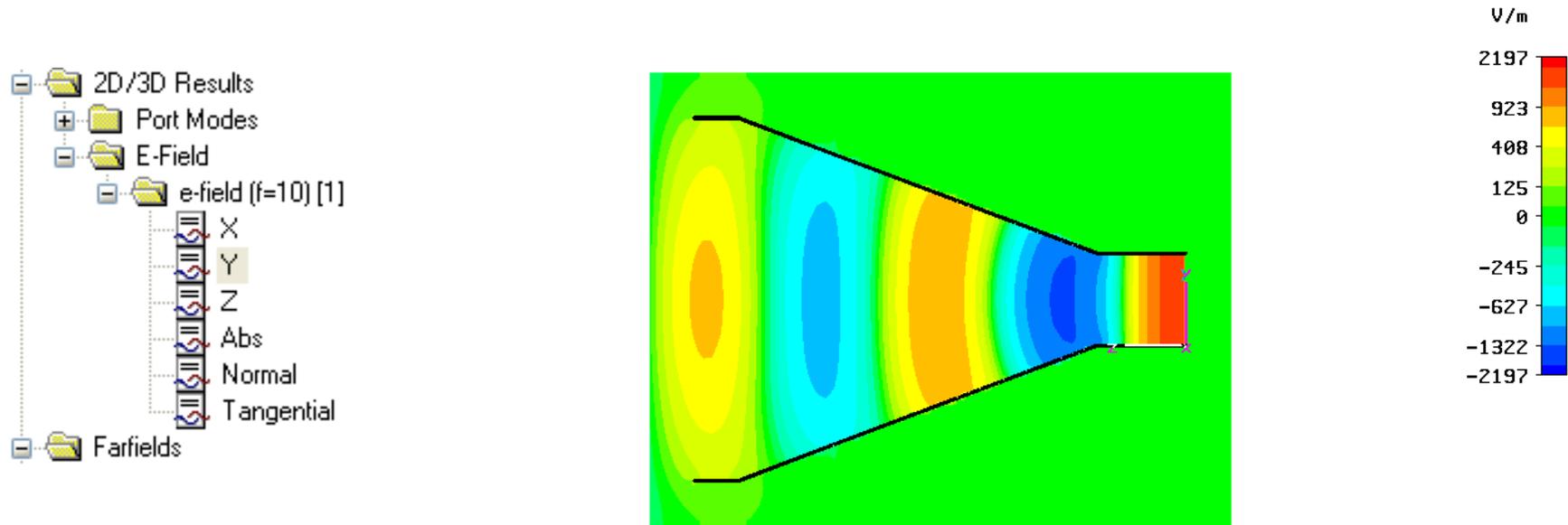
# Analyze 2D/3D Results



Type = E-Field (peak)  
Mode type = TE  
Accuracy =  $4.20634e-015$   
Fcutoff = 5.87719  
Beta = 169.568 1/m  
Wave Imp. = 465.637 Ohms  
  
Plane at z = 0  
Frequency = 10  
Phase = 0 degrees  
Maximum-2d = 1699.1 V/m at 0.5 / 0.25 / 0

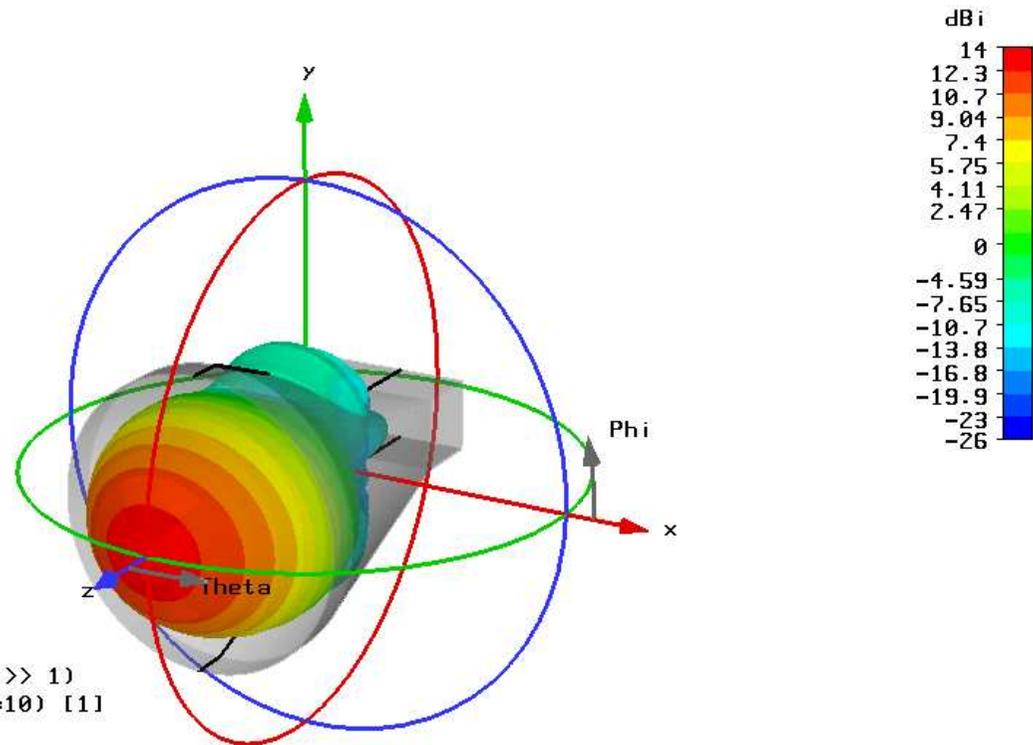
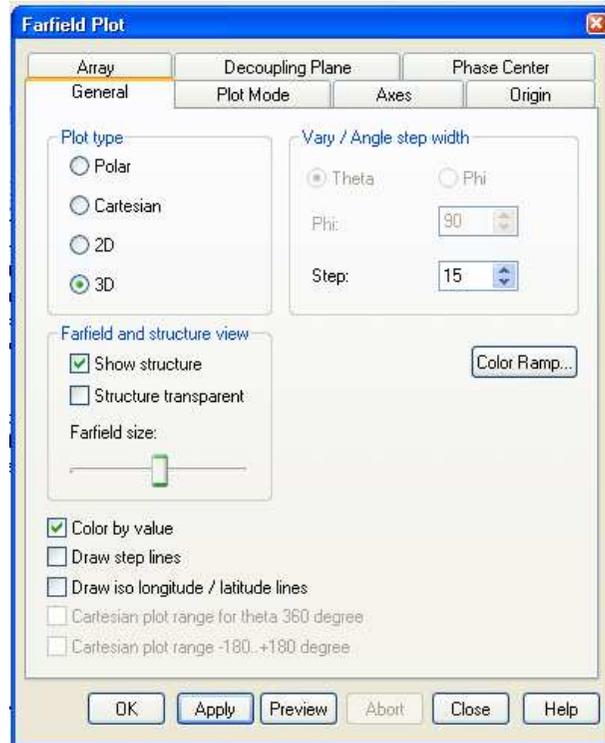


# Electric Field @ 10GHz



Type = E-Field (peak)  
Monitor = e-field (f=10) [1]  
Component = y  
Plane at x = 0.5  
Frequency = 10  
Phase = 0 degrees  
Maximum-2d = 2197.5 V/m at 0.5 / 0.5 / 0.499522

# Far Field @ 10GHz



Type = Farfield  
 Approximation = enabled ( $kR \gg 1$ )  
 Monitor = farfield (f=10) [1]  
 Component = Abs  
 Output = Directivity  
 Frequency = 10  
 Rad. effic. = 0.9980  
 Tot. effic. = 0.9959  
 Dir. = 13.97 dBi

# Copy / Paste of Result Curves

Signal plots and farfield curves can now be copied by using standard copy / paste

